TOSHIBA Field Effect Transistor Silicon N Channel Junction Type

2SK208

General Purpose and Impedance Converter and Condenser Microphone Applications

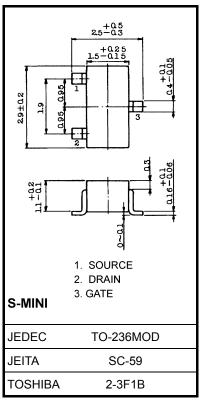
- High breakdown voltage: $V_{GDS} = -50 V$
- High input impedance: $I_{GSS} = -1.0 \text{ nA} (max) (V_{GS} = -30 \text{ V})$
- Low noise: NF = 0.5dB (typ.) (R_G = $100 \text{ k}\Omega$, f = 120 Hz)
- Small package.

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Gate-drain voltage	V _{GDS}	-50	V
Gate current	lG	10	mA
Drain power dissipation	PD	100	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	-55~125	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



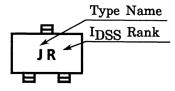
Weight: 0.012 g (typ.)

Characteristics Symbol **Test Condition** Min Typ. Max Unit Gate cut-off current $V_{GS} = -30 \text{ V}, \text{ V}_{DS} = 0$ -1.0 nA IGSS V Gate-drain breakdown voltage V (BR) GDS $V_{DS} = 0, I_G = -100 \ \mu A$ -50 ____ IDSS Drain current V_{DS} = 10 V, V_{GS} = 0 0.3 6.5 mΑ (Note) Gate-source cut-off voltage VGS (OFF) $V_{DS} = 10 V, I_D = 0.1 \mu A$ -0.4 -5.0 V Forward transfer admittance |Y_{fs}| $V_{DS} = 10 V, V_{GS} = 0, f = 1 kHz$ 1.2 mS V_{DS} = 10 V, V_{GS} = 0, f = 1 MHz Input capacitance Ciss 8.2 рF $V_{GD} = -10 \text{ V}, I_D = 0, f = 1 \text{ MHz}$ Reverse transfer capacitance Crss 2.6 ____ pF V_{DS} = 15 V, V_{GS} = 0 NF Noise figure 0.5 dB $R_{G} = 100 \text{ k}\Omega, f = 120 \text{ Hz}$

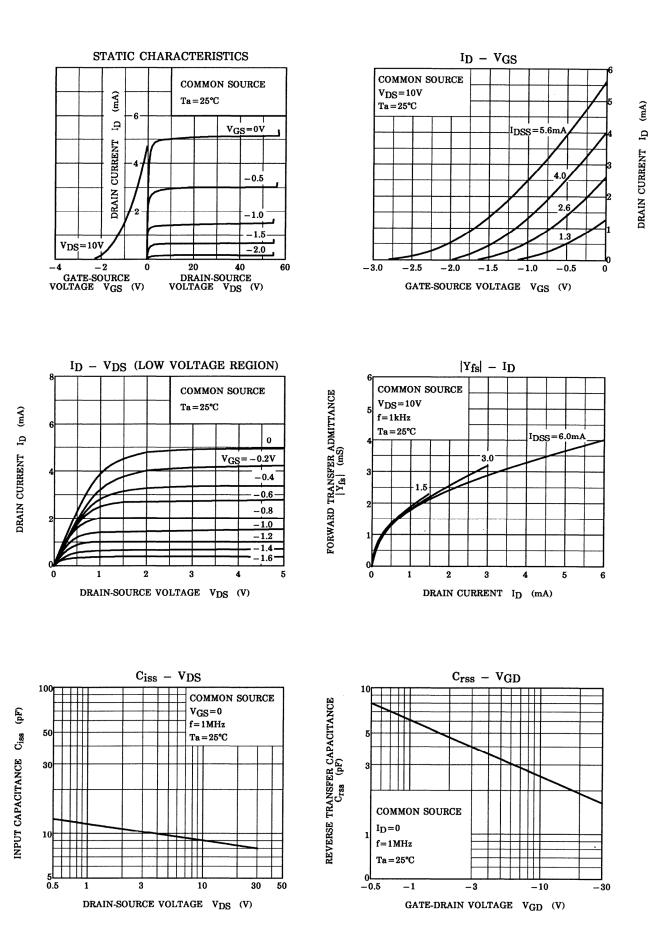
Electrical Characteristics (Ta = 25°C)

Note: I_{DSS} classification R: 0.30~0.75 mA, O: 0.60~1.40 mA, Y: 1.2~3.0 mA, GR: 2.6~6.5 mA

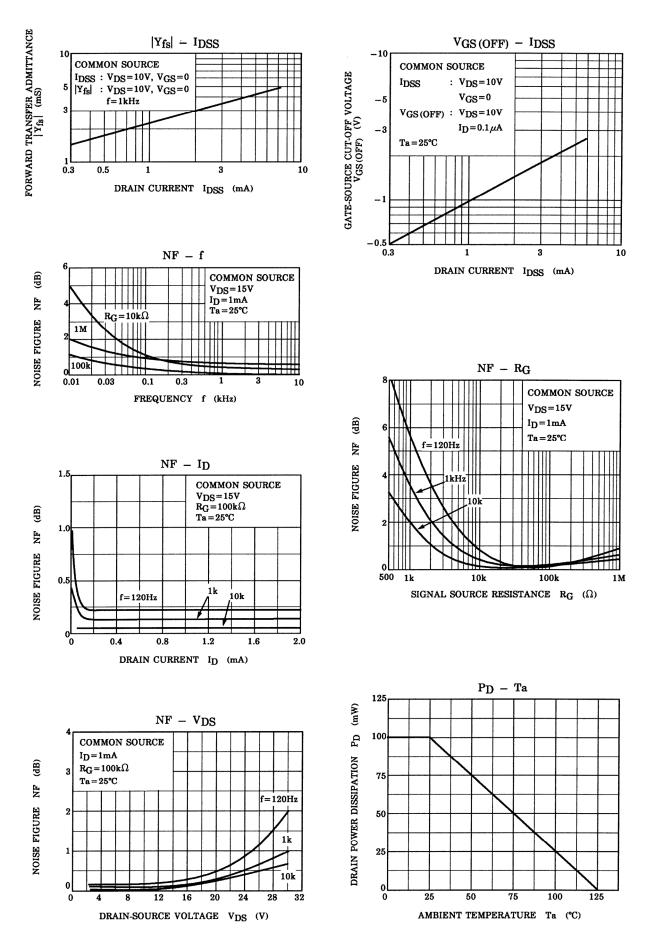
Marking



Unit: mm



TOSHIBA



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20070701-EN GENERAL

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